Low-Voltage CMOS 16-Bit D-Type Flip-Flop

With 5 V–Tolerant Inputs and Outputs (3–State, Non–Inverting)

The MC74LCX16374 is a high performance, non-inverting 16-bit D-type flip-flop operating from a 2.3 V to 3.6 V supply. The device is byte controlled. Each byte has separate Output Enable and Clock Pulse inputs. These control pins can be tied together for full 16-bit operation. High impedance TTL compatible inputs significantly reduce current loading to input drivers while TTL compatible outputs offer improved switching noise performance. A V_I specification of 5.5 V allows MC74LCX16374 inputs to be safely driven from 5.0 V devices.

The MC74LCX16374 consists of 16 edge-triggered flip-flops with individual D-type inputs and 5.0 V-tolerant 3-state true outputs. The buffered clocks (CPn) and buffered Output Enables (\overline{OEn}) are common to all flip-flops within the respective byte. The flip-flops will store the state of individual D inputs that meet the setup and hold time requirements on the LOW-to-HIGH Clock (CP) transition. With the \overline{OE} LOW, the contents of the flip-flops are available at the outputs. When the \overline{OE} is HIGH, the outputs go to the high impedance state. The \overline{OE} input level does not affect the operation of the flip-flops.

Features

- Designed for 2.3 to 3.6 V V_{CC} Operation
- 6.2 ns Maximum t_{pd}
- 5.0 V Tolerant Interface Capability With 5.0 V TTL Logic
- Supports Live Insertion and Withdrawal
- I_{OFF} Specification Guarantees High Impedance When $V_{CC} = 0$ V
- LVTTL Compatible
- LVCMOS Compatible
- 24 mA Balanced Output Sink and Source Capability
- Near Zero Static Supply Current in All Three Logic States (20 μA) Substantially Reduces System Power Requirements
- Latchup Performance Exceeds 500 mA
- ESD Performance: Human Body Model >2000 V; Machine Model >200 V
- These are Pb-Free Devices*



ORDERING INFORMATION

= Wafer Lot

= Work Week

= Year

= Assembly Location

= Pb-Free Package

1

A

WL

YY

G

WW

See detailed ordering and shipping information in the package dimensions section on page 3 of this data sheet.

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

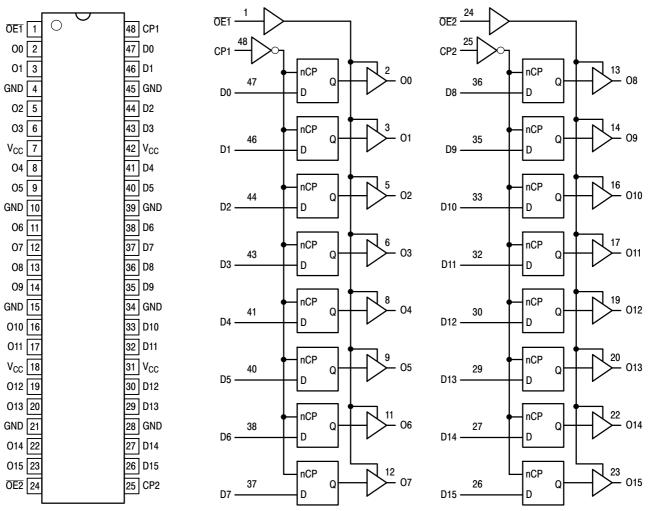


Figure 1. Pinout: 48-Lead (Top View)

Figure 2. Logic Diagram

Table 1. PIN NAMES

Pins	Function	
OEn	Output Enable Inputs	
CPn	Clock Pulse Inputs	
D0-D15	Inputs	
O0-O15	Outputs	

TRUTH TABLE

	Inputs		Outputs		Inputs		Outputs
CP1	OE1	D0:7	O0:7	CP2	OE2	D8:15	O8:15
Ŷ	L	Н	Н	Ŷ	L	Н	Н
↑	L	L	L	1 1	L	L	L
L	L	х	O0	L	L	х	O0
Х	Н	Х	Z	Х	Н	Х	Z

High Voltage Level Н =

Low Voltage Level L =

High Impedance State Z ↑ =

Low-to-High Transition =

Х = High or Low Voltage Level and Transitions Are Acceptable; for I_{CC} reasons, DO NOT FLOAT Inputs

ORDERING INFORMATION

Device	Package	Shipping [†]
MC74LCX16374DT	74LCX16374DT TSSOP-48* 39 Units / Rail	
MC74LCX16374DTG	TSSOP-48* 39 Units / Rail	
MC74LCX16374DTR2	TSSOP-48*	2500 / Tape & Reel
M74LCX16374DTR2G	TSSOP-48*	2500 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D. *This package is inherently Pb-Free.

MAXIMUM RATINGS

Symbol	Parameter	Value	Condition	Unit
V _{CC}	DC Supply Voltage	-0.5 to +7.0		V
VI	DC Input Voltage	$-0.5 \leq V_l \leq +7.0$		V
Vo	DC Output Voltage	$-0.5 \leq V_O \leq +7.0$	Output in 3-State	V
		$-0.5 \le V_O \le V_{CC} + 0.5$	Output in HIGH or LOW State. (Note 1)	V
Ι _{ΙΚ}	DC Input Diode Current	-50	V _I < GND	mA
Ι _{ΟΚ}	DC Output Diode Current	-50	V _O < GND	mA
		+50	V _O > V _{CC}	mA
Ι _Ο	DC Output Source/Sink Current	±50		mA
I _{CC}	DC Supply Current Per Supply Pin	±100		mA
I _{GND}	DC Ground Current Per Ground Pin	±100		mA
T _{STG}	Storage Temperature Range	−65 to +150		°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. I_O absolute maximum rating must be observed.

RECOMMENDED OPERATING CONDITIONS

Symbol	Param	eter	Min	Тур	Max	Unit
V _{CC}	Supply Voltage	Operating Data Retention Only	2.0 1.5	2.5, 3.3 2.5, 3.3	3.6 3.6	V
VI	Input Voltage		0		5.5	V
V _O	Output Voltage	(HIGH or LOW State) (3–State)	0 0		V _{CC} 5.5	V
I _{OH}	HIGH Level Output Current	$V_{CC} = 3.0 \text{ V} - 3.6 \text{ V} \\ V_{CC} = 2.7 \text{ V} - 3.0 \text{ V} \\ V_{CC} = 2.3 \text{ V} - 2.7 \text{ V}$			- 24 - 12 - 8	mA
I _{OL}	LOW Level Output Current	$V_{CC} = 3.0 \text{ V} - 3.6 \text{ V}$ $V_{CC} = 2.7 \text{ V} - 3.0 \text{ V}$ $V_{CC} = 2.3 \text{ V} - 2.7 \text{ V}$			+ 24 + 12 + 8	mA
T _A	Operating Free-Air Temperature		-55		+125	°C
$\Delta t / \Delta V$	Input Transition Rise or Fall Rate, V _{IN} from 0.8 V to 2.0 V, V_{CC} = 3.0 V		0		10	ns/V

DC ELECTRICAL CHARACTERISTICS

			T _A = −55°C	to +125°C	
Symbol	Characteristic	Condition	Min	Min Max	
V _{IH}	HIGH Level Input Voltage (Note 2)	$2.3~V \leq V_{CC} \leq 2.7~V$	1.7		V
		$2.7~V \leq V_{CC} \leq 3.6~V$	2.0		
V_{IL}	LOW Level Input Voltage (Note 2)	$2.3~V \leq V_{CC} \leq 2.7~V$	1	0.7	V
		$2.7~V \leq V_{CC} \leq 3.6~V$	1	0.8	
V _{OH}	HIGH Level Output Voltage	2.3 V \leq V_{CC} \leq 3.6 V; I_{OL} = 100 μA	V _{CC} – 0.2		V
		V_{CC} = 2.3 V; I_{OH} = -8 mA	1.8		
		$V_{CC} = 2.7 \text{ V}; \text{ I}_{OH} = -12 \text{ mA}$	2.2		
		V _{CC} = 3.0 V; I _{OH} = -18 mA	2.4		
		V _{CC} = 3.0 V; I _{OH} = -24 mA	2.2		
V _{OL}	LOW Level Output Voltage	2.3 V \leq V_{CC} \leq 3.6 V; I_{OL} = 100 μA	1	0.2	V
		V _{CC} = 2.3 V; I _{OL} = 8 mA	1	0.6	
		V _{CC} = 2.7 V; I _{OL} = 12 mA	1	0.4	
		V _{CC} = 3.0 V; I _{OL} = 16 mA	1	0.4	1
		V _{CC} = 3.0 V; I _{OL} = 24 mA		0.55	1
lj	Input Leakage Current	2.3 V \leq V _{CC} \leq 3.6 V; 0 V \leq V _I \leq 5.5 V		±5.0	μA
I _{OZ}	3-State Output Current	$\begin{array}{l} 2.3 \leq V_{CC} \leq 3.6 \text{ V}; \text{ OV} \leq V_{O} \leq 5.5 \text{ V}; \\ V_{I} = V_{IH} \text{ or } V_{IL} \end{array}$		±5.0	μΑ
I _{OFF}	Power-Off Leakage Current	$V_{CC} = 0 \text{ V}; \text{ V}_{I} \text{ or } \text{ V}_{O} = 5.5 \text{ V}$		10	μA
I _{CC}	Quiescent Supply Current	$2.3 \leq V_{CC} \leq 3.6$ V; V_I = GND or V_{CC}		20	μA
		$2.3 \leq V_{CC} \leq 3.6$ V; $3.6 \leq V_{I}$ or $V_{O} \leq 5.5$ V	1	±20	μA
ΔI_{CC}	Increase in I _{CC} per Input	$2.3 \le V_{CC} \le 3.6$ V; $V_{IH} = V_{CC} - 0.6$ V		500	μA

2. These values of V_I are used to test DC electrical characteristics only.

AC CHARACTERISTICS t_R = t_F = 2.5 ns; C_L = 50 pF; R_L = 500 Ω

					T _A = -55°C	to +125°C			
			V _{CC} = 3.3 C _L = 5	V ± 0.3 V 50 pF		2.7 V 50 pF		5 V ± 0.2 V 30 pF	
Symbol	Parameter	Waveform	Min	Max	Min	Max	Min	Max	Unit
f _{max}	Clock Pulse Frequency	1	170						MHz
t _{PLH} t _{PHL}	Propagation Delay CP to O _n	1	1.5 1.5	6.2 6.2	1.5 1.5	6.5 6.5	1.5 1.5	7.4 7.4	ns
t _{PZH} t _{PZL}	Output Enable Time to High and Low Level	2	1.5 1.5	6.1 6.1	1.5 1.5	6.3 6.3	1.5 1.5	7.9 7.9	ns
t _{PHZ} t _{PLZ}	Output Disable Time From High and Low Level	2	1.5 1.5	6.0 6.0	1.5 1.5	6.2 6.2	1.5 1.5	7.2 7.2	ns
t _s	Setup Time, HIGH or LOW D ⁿ to CP	1	2.5		2.5		3.0		ns
t _h	Hold Time, HIGH or LOW D ⁿ to CP	1	1.5		1.5		2.0		ns
t _w	CP Pulse Width, HIGH	3	3.0		3.0		3.5		ns
t _{OSHL} t _{OSLH}	Output-to-Output Skew (Note 3)			1.0 1.0					ns

 Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}); parameter guaranteed by design.

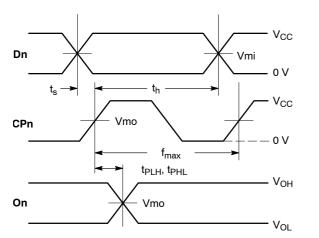
DYNAMIC SWITCHING CHARACTERISTICS

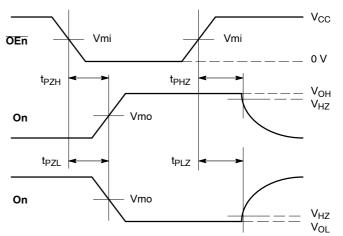
				T _A = +25°C		
Symbol	Characteristic	Condition	Min	Тур	Max	Unit
V _{OLP}	Dynamic LOW Peak Voltage (Note 4)	$ \begin{array}{l} {\sf V}_{CC} = 3.3 \; {\sf V}, \; {\sf C}_L = 50 \; {\sf pF}, \; {\sf V}_{IH} = 3.3 \; {\sf V}, \; {\sf V}_{IL} = 0 \; {\sf V} \\ {\sf V}_{CC} = 2.5 \; {\sf V}, \; {\sf C}_L = 30 \; {\sf pF}, \; {\sf V}_{IH} = 2.5 \; {\sf V}, \; {\sf V}_{IL} = 0 \; {\sf V} \end{array} $		0.8 0.6		V V
V _{OLV}	Dynamic LOW Valley Voltage (Note 4)	$ \begin{array}{l} V_{CC} = 3.3 \text{ V}, \ C_L = 50 \text{ pF}, \ V_{IH} = 3.3 \text{ V}, \ V_{IL} = 0 \text{ V} \\ V_{CC} = 2.5 \text{ V}, \ C_L = 30 \text{ pF}, \ V_{IH} = 2.5 \text{ V}, \ V_{IL} = 0 \text{ V} \end{array} $		-0.8 -0.6		V V

4. Number of outputs defined as "n". Measured with "n-1" outputs switching from HIGH-to-LOW or LOW-to-HIGH. The remaining output is measured in the LOW state.

CAPACITIVE CHARACTERISTICS

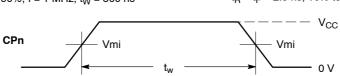
Symbol	Parameter	Condition	Typical	Unit
C _{IN}	Input Capacitance	V_{CC} = 3.3 V, V_{I} = 0 V or V_{CC}	7	pF
C _{OUT}	Output Capacitance	V_{CC} = 3.3 V, V_I = 0 V or V_{CC}	8	pF
C _{PD}	Power Dissipation Capacitance	10 MHz, V_{CC} = 3.3 V, V_{I} = 0 V or V_{CC}	20	pF





WAVEFORM 1 – PROPAGATION DELAYS, SETUP AND HOLD TIMES $t_B = t_F = 2.5$ ns, 10% to 90%; f = 1 MHz; $t_W = 500$ ns

WAVEFORM 2 – OUTPUT ENABLE AND DISABLE TIMES $t_R = t_F = 2.5$ ns, 10% to 90%; f = 1 MHz; $t_W = 500$ ns



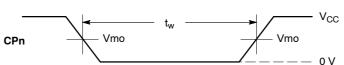


Figure	3.	AC	Waveforms
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Table 2. AC WAVEFORMS

		V _{CC}					
Symbol	3.3 V \pm 0.3 V	2.7 V	$2.5 \text{ V} \pm 0.2 \text{ V}$				
Vmi	1.5 V	1.5 V	V _{CC} / 2				
Vmo	1.5 V	1.5 V	V _{CC} / 2				
V _{HZ}	V _{OL} + 0.3 V	V _{OL} + 0.3 V	V _{OL} + 0.15 V				
V _{LZ}	V _{OH} – 0.3 V	V _{OH} – 0.3 V	V _{OH} – 0.15 V				

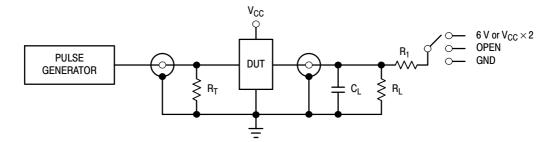




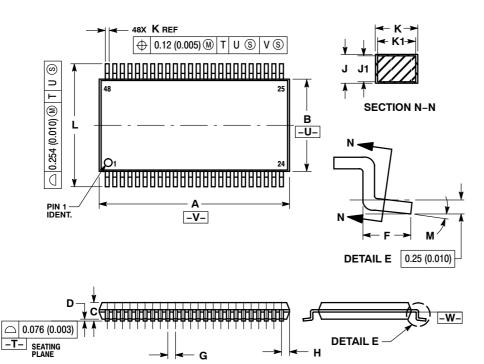
Table 3. TEST CIRCUIT

TEST	SWITCH
t _{PLH} , t _{PHL}	Open
t _{PZL} , t _{PLZ}	6 V at V_{CC} = $~3.3\pm0.3$ V 6 V at V_{CC} = $~2.5\pm0.2$ V
Open Collector/Drain $t_{\mbox{PLH}}$ and $t_{\mbox{PHL}}$	6 V
t _{PZH} , t _{PHZ}	GND

 C_L = 50 pF at V_{CC} = 3.3 \pm 0.3 V or equivalent (includes jig and probe capacitance) C_L = 30 pF at V_{CC} = 2.5 \pm 0.2 V or equivalent (includes jig and probe capacitance) R_L = R_1 = 500 Ω or equivalent R_T = Z_{OUT} of pulse generator (typically 50 Ω)

PACKAGE DIMENSIONS

TSSOP-48 DT SUFFIX CASE 1201-01 ISSUE A



NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 CONTROLLING DIMENSION: MILLIMETER.
- CONTROLLING DIMENSION: MILLIMETER.
 DIMENSIONS A AND B DO NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
 DIMENSION K DOES NOT INCLUDE DAMBAR
- DIMENSION K DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE K DIMENSION AT MAXIMUM MATERIAL CONDITION.
- TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.
 DIMENSIONS A AND B ARE TO BE
- DIMENSIONS A AND B ARE TO BE DETERMINED AT DATUM PLANE -W-

	MILLIMETERS		INCHES	
DIM	MIN	MAX	MIN	MAX
Α	12.40	12.60	0.488	0.496
В	6.00	6.20	0.236	0.244
C		1.10		0.043
D	0.05	0.15	0.002	0.006
F	0.50	0.75	0.020	0.030
G	0.50 BSC		0.0197 BSC	
Н	0.37		0.015	
J	0.09	0.20	0.004	0.008
J1	0.09	0.16	0.004	0.006
K	0.17	0.27	0.007	0.011
K1	0.17	0.23	0.007	0.009
L	7.95	8.25	0.313	0.325
Μ	0 °	8 °	0 °	8 °

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